

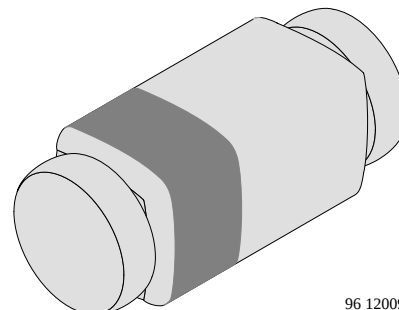
Schottky Barrier Diodes

Features

- Integrated protection ring against static discharge
- Low capacitance
- Low leakage current
- Low forward voltage drop

Applications

HF–Detector
Protection circuit
Diode for low currents with a low supply voltage
Small battery charger
Power supplies
DC / DC converter for notebooks



96 12009

Absolute Maximum Ratings

 $T_j = 25^{\circ}\text{C}$

Parameter	Test Conditions	Type	Symbol	Value	Unit
Reverse voltage		LS101A	V_R	60	V
		LS101B	V_R	50	V
		LS101C	V_R	40	V
Peak forward surge current	$t_p=10\mu\text{s}$		I_{FSM}	2	A
Repetitive peak forward current			I_{FRM}	150	mA
Forward current			I_F	30	mA
Junction temperature			T_j	125	$^{\circ}\text{C}$
Storage temperature range			T_{stg}	$-65...+150$	$^{\circ}\text{C}$

Maximum Thermal Resistance

 $T_j = 25^{\circ}\text{C}$

Parameter	Test Conditions	Symbol	Value	Unit
Junction ambient	on PC board 50mmx50mmx1.6mm	R_{thJA}	320	K/W

Electrical Characteristics

$T_j = 25^\circ\text{C}$

Parameter	Test Conditions	Type	Symbol	Min	Typ	Max	Unit
Reverse Breakdown Voltage	$I_R = 10\mu\text{A}$	LS101A	$V_{(BR)R}$	60			V
		LS101B	$V_{(BR)R}$	50			V
		LS101C	$V_{(BR)R}$	40			V
Leakage current	$V_R = 50\text{V}$	LS101A	I_R			200	nA
	$V_R = 40\text{V}$	LS101B	I_R			200	nA
	$V_R = 30\text{V}$	LS101C	I_R			200	nA
Forward voltage drop	$I_F = 1\text{mA}$	LS101A	V_F			0.41	V
		LS101B	V_F			0.4	V
		LS101C	V_F			0.39	V
	$I_F = 15\text{mA}$	LS101A	V_F			1	V
		LS101B	V_F			0.95	V
		LS101C	V_F			0.9	V
Diode capacitance	$V_R = 0\text{V}, f = 1\text{MHz}$	LS101A	C_D			2.0	pF
		LS101B	C_D			2.1	pF
		LS101C	C_D			2.2	pF

Characteristics ($T_j = 25^\circ\text{C}$ unless otherwise specified)

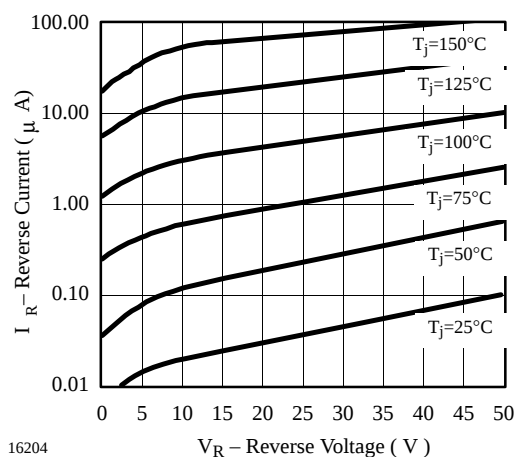


Figure 1. Reverse Current vs. Reverse Voltage

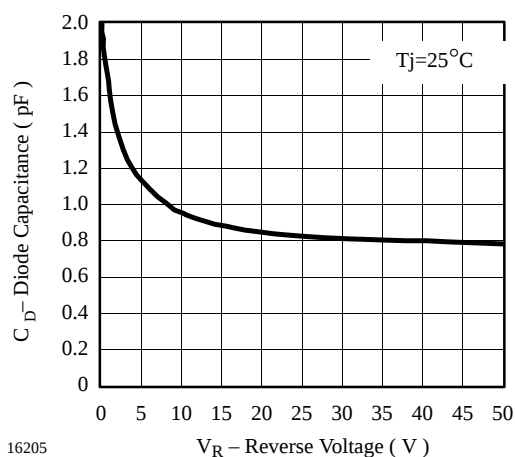


Figure 2. Diode Capacitance vs. Reverse Voltage

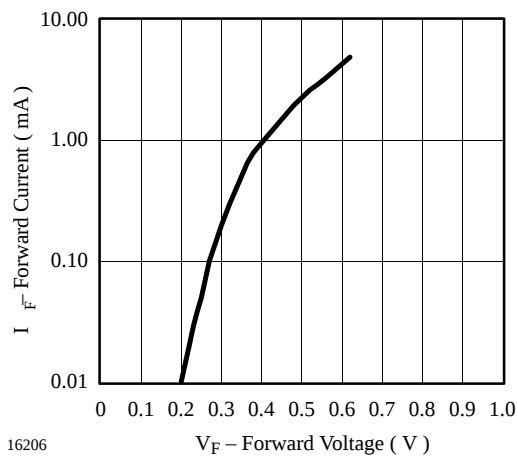
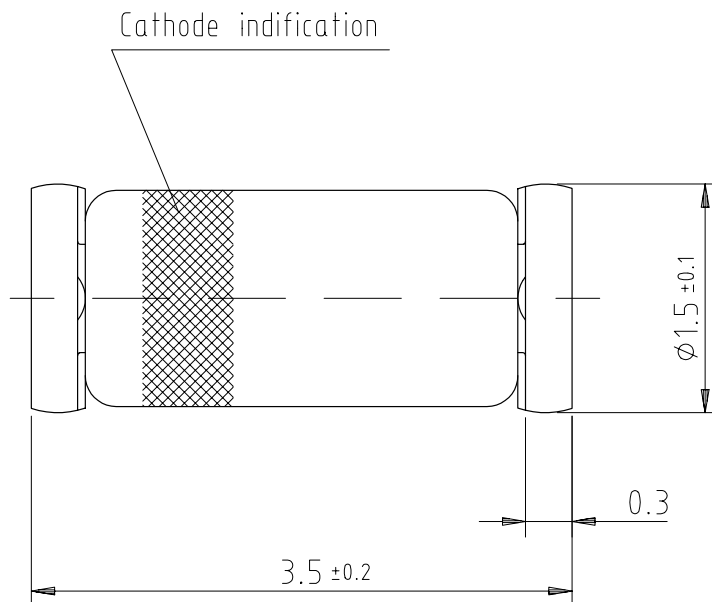
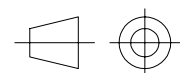
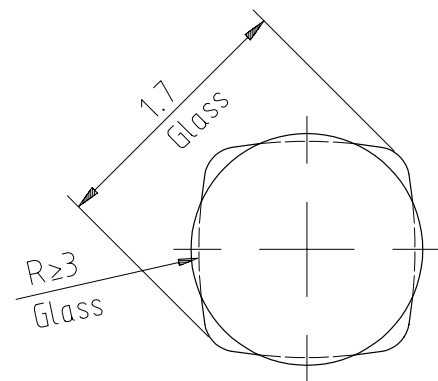


Figure 3. Forward Current vs. Forward Voltage

Dimensions in mm



Glass case
Quadro MELF
similar to JEDEC 213 AA



technical drawings
according to DIN
specifications

96 12071

Ozone Depleting Substances Policy Statement

It is the policy of **Vishay Semiconductor GmbH** to

1. Meet all present and future national and international statutory requirements.
2. Regularly and continuously improve the performance of our products, processes, distribution and operating systems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).

The Montreal Protocol (1987) and its London Amendments (1990) intend to severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

Vishay Semiconductor GmbH has been able to use its policy of continuous improvements to eliminate the use of ODSs listed in the following documents.

1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively
2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA
3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

Vishay Semiconductor GmbH can certify that our semiconductors are not manufactured with ozone depleting substances and do not contain such substances.

We reserve the right to make changes to improve technical design and may do so without further notice.

Parameters can vary in different applications. All operating parameters must be validated for each customer application by the customer. Should the buyer use Vishay-Telefunken products for any unintended or unauthorized application, the buyer shall indemnify Vishay-Telefunken against all claims, costs, damages, and expenses, arising out of, directly or indirectly, any claim of personal damage, injury or death associated with such unintended or unauthorized use.

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